

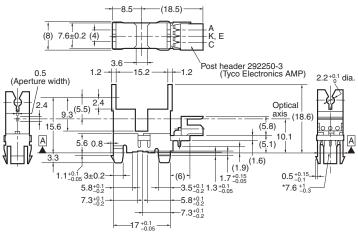
Photomicrosensor (Actuator Mounted) E-SA107-P2

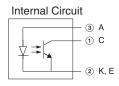


Be sure to read Precautions on page 24.

Dimensions

Note: All units are in millimeters unless otherwise indicated.





Terminal No.	Name	
Α	Anode	
K	Cathode	
С	Collector	
E	Emitter	

Note: The asterisked dimension is specified by datum A only.

Unless otherwise specified, the tolerances are as shown below.

Dimensions	Tolerance
3 mm max.	±0.3
3 < mm £ 6	±0.375
6 < mm £ 10	±0.45
10 < mm £ 18	±0.55
18 < mm £ 30	±0.65

Recommended Mating Connectors: 179228-3 (crimp connector) 173977-3 (press-fit connector) Tyco Electronics AMP

175778-3 (crimp connector)

Features

- An actuator can be attached.
- Snap-in mounting model.
- Mounts to 1.0-, 1.2- and 1.6-mm-thick PCBs.
- Connects to Tyco Electronics AMP's CT-series connectors.

■ Absolute Maximum Ratings (Ta = 25°C)

Item		Symbol	Rated value
Emitter	Forward current	I _F	50 mA (see note)
	Pulse forward cur- rent	I _{FP}	
	Reverse voltage	V_R	4 V
Detector	Collector–Emitter voltage	V _{CEO}	30 V
	Emitter-Collector voltage	V _{ECO}	5 V
	Collector current	I _C	20 mA
	Collector dissipa- tion	P _C	100 mW (see note)
Ambient tem-	Operating	Topr	–25°C to 85°C
perature	Storage	Tstg	–40°C to 85°C
Soldering temp	erature	Tsol	

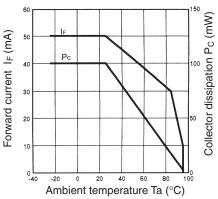
Note: Refer to the temperature rating chart if the ambient temperature exceeds 25°C.

■ Electrical and Optical Characteristics (Ta = 25°C)

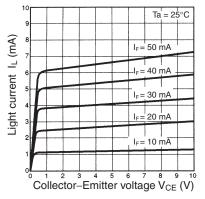
	Item	Symbol	Value	Condition
Emitter	Forward voltage	V_{F}	1.2 V typ., 1.5 V max.	I _F = 30 mA
	Reverse current	I _R	0.01 μA typ., 10 μA max.	V _R = 4 V
	Peak emission wavelength	λ_{P}	940 nm typ.	I _F = 30 mA
Detector	Light current	I _L	0.5 mA min., 14 mA max.	I _F = 20 mA, V _{CE} = 5 V
	Dark current	I _D	200 nA max.	V _{CE} = 10 V, 0 ℓx
	Leakage current	I _{LEAK}		
	Collector–Emitter saturated voltage	V _{CE} (sat)	0.1 V typ., 0.4 V max.	$I_F = 20 \text{ mA}, I_L = 0.3 \text{ mA}$
	Peak spectral sensitivity wave- length	λ_{P}	850 nm typ.	V _{CE} = 5 V
Rising time	·	tr	8 μs typ.	$V_{CC} = 5 \text{ V}, R_L = 100 \Omega, I_L = 1 \text{ mA}$
Falling time		tf	8 μs typ.	$V_{CC} = 5 \text{ V}, R_L = 100 \Omega, I_L = 1 \text{ mA}$

■ Engineering Data

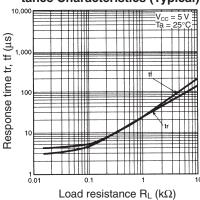
Forward Current vs. Collector Dissipation Temperature Rating



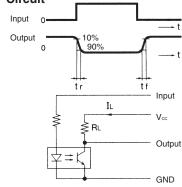
Light Current vs. Collector–Emitter Voltage Characteristics (Typical)



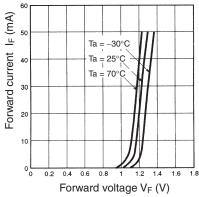
Response Time vs. Load Resistance Characteristics (Typical)



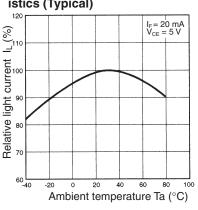
Response Time Measurement Circuit



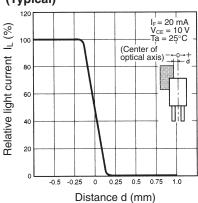
Forward Current vs. Forward Voltage Characteristics (Typical)



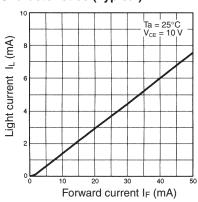
Relative Light Current vs. Ambient Temperature Characteristics (Typical)



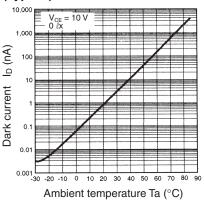
Sensing Position Characteristics (Typical)



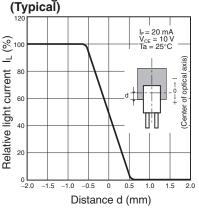
Light Current vs. Forward Current Characteristics (Typical)



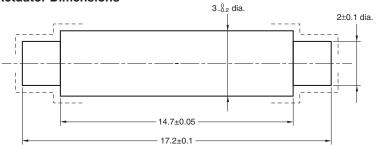
Dark Current vs. Ambient Temperature Characteristics (Typical)



Sensing Position Characteristics



Actuator Dimensions



ote: 1. Make sure that the portions marked with dotted lines have no burrs.

2. The material of the actuator must be selected by considering the infrared permeability of the actuator.

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